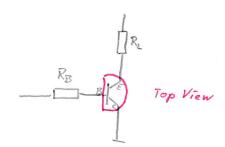


## Discrete POWER & Signal **Technologies**

**BC547 BC547A BC547B BC547C** 





## **NPN General Purpose Amplifier**

This device is designed for use as general purpose amplifiers and switches requiring collector currents to 300 mA. Sourced from Process 10. See PN100A for characteristics.

### **Absolute Maximum Ratings\***

TA = 25°C unless otherwise noted

Symbol	Parameter	Value	Units
V <sub>CEO</sub>	Collector-Emitter Voltage	45	V
V <sub>CES</sub>	Collector-Base Voltage	50	V
V <sub>EBO</sub>	Emitter-Base Voltage	6.0	V
Ic	Collector Current - Continuous	500	mA
T <sub>.l</sub> , T <sub>sta</sub>	Operating and Storage Junction Temperature Range	-55 to +150	°C

<sup>\*</sup>These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

NOTES:

1) These ratings are based on a maximum junction temperature of 150 degrees C.

2) These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.

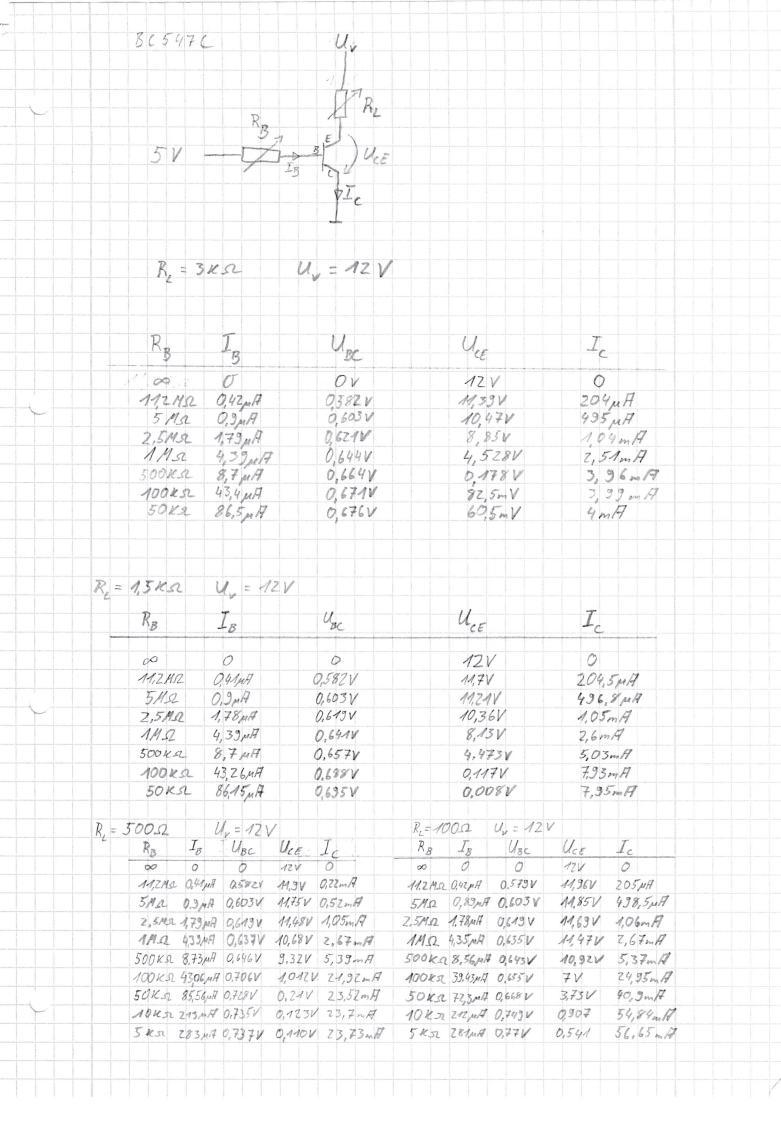
## **Thermal Characteristics**

TA = 25°C unless otherwise noted

Symbol	Characteristic	Max	Units
		BC547 / A / B / C	
P <sub>D</sub>	Total Device Dissipation Derate above 25°C	625 5.0	mW mW/°C
R <sub>θJC</sub>	Thermal Resistance, Junction to Case	83.3	°C/W
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	200	. °C/W

# NPN General Purpose Amplifier (continued)

Symbol	Parameter	Test Conditions	Min	Max	Units
OFF CHA	RACTERISTICS				1
V <sub>(BR)CEO</sub>	Collector-Emitter Breakdown Voltage	I <sub>C</sub> = 1.0 mA, I <sub>B</sub> = 0	45	T	T v
V <sub>(BR)CBO</sub>	Collector-Base Breakdown Voltage	$I_{C} = 10  \mu A, I_{E} = 0$	50		V
V <sub>(BR)CES</sub>	Collector-Base Breakdown Voltage	$I_{\rm C} = 10  \mu \text{A}, I_{\rm E} = 0$	50		V
V <sub>(BR)EBO</sub>	Emitter-Base Breakdown Voltage	$I_E = 10  \mu A, I_C = 0$	6.0		V
I <sub>CBO</sub>	Collector Cutoff Current	V <sub>CB</sub> = 30 V, I <sub>E</sub> = 0 V <sub>CB</sub> = 30 V, I <sub>E</sub> = 0, T <sub>A</sub> = +150 °C		15 5.0	nA μA
	ACTERISTICS DC Current Gain	V <sub>CF</sub> = 5.0 V, I <sub>C</sub> = 2.0 mA <b>547</b>	110	800	
ON CHAR		547A 547B	110 200	220 450	
h <sub>FE</sub>		547A 547B 547C I <sub>C</sub> = 10 mA, I <sub>B</sub> = 0.5 mA	110	220 450 800 0.25	V
	DC Current Gain	547A 547B 547C	110 200	220 450 800	1
$h_{FE}$ $V_{CE(sat)}$ $V_{BE(on)}$	DC Current Gain  Collector-Emitter Saturation Voltage	547A 547B 547C I <sub>C</sub> = 10 mA, I <sub>B</sub> = 0.5 mA I <sub>C</sub> = 100 mA, I <sub>B</sub> = 5.0 mA V <sub>CE</sub> = 5.0 V, I <sub>C</sub> = 2.0 mA	110 200 420	220 450 800 0.25 0.60 0.70	V
$h_{\text{FE}}$ $V_{\text{CE(sat)}}$ $V_{\text{BE(on)}}$	DC Current Gain  Collector-Emitter Saturation Voltage  Base-Emitter On Voltage	547A 547B 547C I <sub>C</sub> = 10 mA, I <sub>B</sub> = 0.5 mA I <sub>C</sub> = 100 mA, I <sub>B</sub> = 5.0 mA V <sub>CE</sub> = 5.0 V, I <sub>C</sub> = 2.0 mA	110 200 420	220 450 800 0.25 0.60 0.70	V



			Uv					The state of the s
	BC54	174		R	= 3Ks2	U. = 5V		Additional and the second and the se
			FR					
			7	$R_{\mathcal{B}}$	$T_{\mathcal{B}}$	UBC	UcE	Ic
		R <sub>3</sub>	, 6	00	0	0	5V	0
		5V IZ	TO UIR	11,21152	0,42mA	0,582V	4,320V	135,9MA
			18 2	3Msz	0,3 MA	0,605V	4.7341	475,9 MA
			1/1c	2,5MSZ	1.78 mH	0,623V	4.423V	984 MA
				1110	4,39mA	0,646V	3,541V	2,466m/7
				500KSL	8,7,417	0,664V	2,1288	4,823mA
					43, 14 MA	0,698 V	0,134V	9,76mA
				50KR	85,38AR	0,703V	0,1V	9,82m/7
					25,67 MA	0.721V	0,0541	9,92mH
				5KS2 8	37,3MA	0,734V	0,039V	9,95mA
	R = 1,5KR	U=5V	600			Uv = 5V		SAL SALES
1 A 1 A 1 A 1 A 1 A 1 A 1 A 1 A 1 A 1 A	$R_{\mathcal{B}}$ $I_{\mathcal{B}}$	Usc Vet	Ic	$R_{\mathcal{B}}$	$I_{\mathcal{B}}$	UBC	Vce	Ic
	00 0	0 5V	0	00	0	0	5V	0
	11,2M2 0,41/18	0,582V 4,922V		11,2 1/32	0,4,00,4	0,5811	4,321	0,22mH
	5MS2 0,9MA	0,605V 4,784V		5/1/2	0,88 pt 7	0.6041	4,788V	0,48mH
	2,5M2 1,77pH	0,623V 4,529V		2,5/152	1,74417	0,6ZZV	4,5411	0,38 m17
	1140 4,2349	0,645V 3,808V	2,43m/7	11152	4,27,47	0.645V	3,813V	2,42 mA
	500KSL 8,48pmH	0.663V Z,640V			8, 47pm A	0,652V	Z,646 W	4.76mH
	100KS2 42,13 MA	0,697V 0,135V		100KS2		0,6371	0,136V	9,76mf7
	50x52 84,17,417	0,703V 0,101V			83,65µA	0702V	0,1011	9,82 m F
	10KSL 416, 33,47	THE THE PARTY OF T	9,92mH	10kg		0.721	0,05ZV	9,92 m A
	5 K.D. 815,2 MA	0,733V 0,04V	9,95mA	5Ks	SAULA	0,733V	0,044	9,95mH
	D - 1000 11							
		= 5V	T					Biological Control of the Control of
	$R_3$ $I_B$	UBC UCE	Ic					
	11,2M2 0,4MA	0 5V	0. Z-1 un A					
	11,2MS 0,4MA 5MS 0,87MA	0577V 5V	0,48 m F					
	2,5MS2 1,75MF	0,604V 4,373V 0,622V 4,322V	and the second section of the second section of the second section is a second section of the second section of the second section sec					
	14.02 9,28,417	0,6444 4,7724	2,45m/7					
		0,658V 4,523V	and the same the same and the s					
-	500 KSZ 41,83,417	0,695V Z,66V	23,05m/7					
	50KSL 83,15 pelt	0,721 1,2021						
	10 KSZ 408,3 M/7	0,772V 0,176V						
	5 KSZ 806,5 MA	0,786V 0,133V						
	5 K SC 000,5 MIT	0,1000 0,1000	47,0 mil					
4			Establishment (EST)					
1								

